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Li_{1.0}Nb_{0.6}Ti_{0.5}O₃陶瓷的低温烧结其微波介电性能

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摘要

研究了以Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ (LNT) 陶瓷为基体, B₂O₃-ZnO-La₂O₃ (BZL) 玻璃为烧结助剂的复合材料的低温烧结行为及微波介电特性。研究表明,BZL玻璃能有效降低LNT陶瓷的烧结温度,掺入10wt% BZL玻璃的复合材料能够在900℃烧结致密。XRD与SEM分析结果表明,添加BZL玻璃的样品烧结后含有LNT和LaNbTiO₆两种晶相,其中LaNbTiO₆相是LNT与BZL玻璃在烧结过程中发生化学反应的产物。在LNT陶瓷中添加BZL玻璃使材料的介电常数和品质因数下降,但有助于减小体系的谐振频率温度系数。掺入10wt% BZL 玻璃的复合材料在900℃烧结2h 后获得了比较满意的微波介电特性:介电常数 $k \approx 58$, 品质因数 $Q \times f \approx 4800\text{GHz}$, 谐振频率温度系数 $\tau_f \approx 11 \times 10^{-6}/^\circ\text{C}$ 。

关键词 [Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ 陶瓷](#) [低温烧结](#) [介电性能](#) [B₂O₃-ZnO-La₂O₃玻璃](#)

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Low Temperature Sintering and Microwave Dielectric Properties of Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ Ceramics

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Abstract Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ (LNT) ceramics were prepared at 900℃ by adding B₂O₃-ZnO-La₂O₃ (BLZ) glass as sintering agent, and the densification process and the microwave dielectric properties of the material were investigated. The results show that the BLZ glass can effectively decrease the sintering temperature of the material. Beside the main crystal phase Li_{1.0}Nb_{0.6}Ti_{0.5}O₃, LaNbTiO₆ is found in the material, which is believed to be the product of the reaction between LNT and BLZ glass during sintering. Adding BLZ glass to LNT ceramics leads to the decrease of dielectric constant k and the quality factor $Q \times f$ of the material, but at the same time, helps to improve the temperature coefficient of resonant frequency τ_f . The low firing Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ ceramic is possessed with $k \approx 8$, $Q \times f \approx 4800\text{GHz}$ and $\tau_f \approx 11 \times 10^{-6}/^\circ\text{C}$.

Key words [Li_{1.0}Nb_{0.6}Ti_{0.5}O₃ ceramics](#) [low firing](#) [dielectric properties](#) [B₂O₃-ZnO-La₂O₃ glass](#)

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